## Bidirectional Switch with IGBT <br> and fast Diode Bridge <br> in ISOPLUS i4-PAC ${ }^{\text {TM }}$

| IGBT |  |  |  |
| :--- | :--- | :---: | :---: |
| Symbol | Conditions | Maximum Ratings |  |
| $\mathrm{V}_{\text {CES }}$ | $\mathrm{T}_{\mathrm{VJ}}=25^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$ | 1200 | V |
| $\mathrm{~V}_{\text {GES }}$ |  | $\pm 20$ | V |
| $\mathrm{I}_{\mathrm{C} 25}$ | $\mathrm{~T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ | 50 | A |
| $\mathrm{I}_{\mathrm{C90}}$ | $\mathrm{~T}_{\mathrm{C}}=90^{\circ} \mathrm{C}$ | 32 | A |
| $\mathrm{I}_{\mathrm{CM}}$ | $\mathrm{V}_{\mathrm{GE}}= \pm 15 \mathrm{~V} ; \mathrm{R}_{\mathrm{G}}=39 \Omega ; \mathrm{T}_{\mathrm{VJ}}=125^{\circ} \mathrm{C}$ | 50 | A |
| $\mathrm{~V}_{\mathrm{CEK}}$ | $\mathrm{RBSOA}, \mathrm{Clamped}$ inductive load; $\mathrm{L}=100 \mu \mathrm{H}$ | $\mathrm{V}_{\mathrm{CES}}$ |  |
| $\mathrm{t}_{\mathrm{SC}}$ | $\mathrm{V}_{\mathrm{CE}}=900 \mathrm{~V} ; \mathrm{V}_{\mathrm{GE}}= \pm 15 \mathrm{~V} ; \mathrm{R}_{\mathrm{G}}=39 \Omega ; \mathrm{T}_{\mathrm{VJ}}=125^{\circ} \mathrm{C}$ | 10 | $\mu \mathrm{~s}$ |
| (SCSOA) | non-repetitive |  |  |
| $\mathbf{P}_{\text {tot }}$ | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ |  | 200 |

Symbol
Conditions
Characteristic Values
( $\mathrm{T}_{\mathrm{vJ}}=25^{\circ} \mathrm{C}$, unless otherwise specified) min. typ. max.

| $\mathrm{V}_{\mathrm{CE} \text { (sat) }}$ | $\begin{array}{r} \mathrm{I}_{\mathrm{C}}=30 \mathrm{~A} ; \mathrm{V}_{\mathrm{GE}}=15 \mathrm{~V} ; \mathrm{T}_{\mathrm{VJ}}=25^{\circ} \mathrm{C} \\ \mathrm{~T}_{\mathrm{VJ}}=125^{\circ} \mathrm{C} \end{array}$ |  | $\begin{aligned} & 2.0 \\ & 2.3 \end{aligned}$ | 2.6 | V |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\text {GE(th) }}$ | $\mathrm{I}_{\mathrm{C}}=1 \mathrm{~mA} ; \mathrm{V}_{\mathrm{GE}}=\mathrm{V}_{\text {CE }}$ | 4.5 |  | 6.5 | V |
| $\mathrm{I}_{\text {ces }}$ | $\begin{array}{r} \mathrm{V}_{\mathrm{CE}}=\mathrm{V}_{\mathrm{CES}} ; \mathrm{V}_{\mathrm{GE}}=0 \mathrm{~V} ; \mathrm{T}_{\mathrm{VJ}}=25^{\circ} \mathrm{C} \\ \mathrm{~T}_{\mathrm{VJ}}=125^{\circ} \mathrm{C} \end{array}$ |  | 0.4 | 0.4 | mA mA |
| $\mathrm{I}_{\text {GES }}$ | $\mathrm{V}_{\mathrm{CE}}=0 \mathrm{~V} ; \mathrm{V}_{\mathrm{GE}}= \pm 20 \mathrm{~V}$ |  |  | 200 | nA |
|  | , ${ }^{\text {a }}$ Inductive load, $\mathrm{T}_{\mathrm{VJ}}=125^{\circ} \mathrm{C}$ |  | $\begin{array}{r} 150 \\ 60 \\ 700 \\ 50 \\ 3.6 \\ 3.0 \end{array}$ |  | ns ns ns ns mJ mJ |
| $\begin{aligned} & \mathbf{C}_{\text {ies }} \\ & \mathbf{Q}_{\text {Gon }} \end{aligned}$ | $\begin{aligned} & V_{C E}=25 \mathrm{~V} ; \mathrm{V}_{\mathrm{GE}}=0 \mathrm{~V} ; f=1 \mathrm{MHz} \\ & \mathrm{~V}_{\mathrm{CE}}=600 \mathrm{~V} ; \mathrm{V}_{\mathrm{GE}}=15 \mathrm{~V} ; \mathrm{I}_{\mathrm{C}}=30 \mathrm{~A} \end{aligned}$ |  | $\begin{array}{r} 2 \\ 250 \end{array}$ |  | nF |
| $\begin{aligned} & \mathbf{R}_{\mathrm{thhc}} \\ & \mathbf{R}_{\mathrm{th} \mathrm{~h} \mathrm{~s}} \\ & \hline \end{aligned}$ |  |  | 1.2 | 0.6 | $\begin{aligned} & \text { KW } \\ & \text { KW } \end{aligned}$ |



## Features

- IGBT
- low saturation voltage
- positive temperature coefficient for easy paralleling
- fast switching
- short tail current for optimized performance in resonant circuits
- HiPerFRED ${ }^{\text {TM }}$ diodes
- fast reverse recovery
- low operating forward voltage
- low leakage current
- ISOPLUS i4-PAC ${ }^{\text {TM }}$ package
- isolated back surface
- low coupling capacity between pins and heatsink
- enlarged creepage towards heatsink
- application friendly pinout
- low inductive current path
- high reliability
- industry standard outline


## Applications

switches to control bidirectional current flow by a single control signal:

- matrix converters
- spare matrix converters
- AC controllers

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| :--- | :--- | ---: |
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| Diodes |  |  |  |
| :--- | :--- | :--- | :--- |
| Symbol | Conditions | Maximum Ratings |  |
| $\mathrm{I}_{\text {F25 }}$ | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ | 48 | A |
| $\mathrm{I}_{\text {F90 }}$ | $\mathrm{T}_{\mathrm{C}}=90^{\circ} \mathrm{C}$ | 25 | A |


| Symbol | Conditions | Characteristic Values <br> min. |  |  | typ. |
| :--- | :--- | ---: | ---: | ---: | ---: |
|  | max. |  |  |  |  |


| Component |  |  |  |
| :--- | :--- | :---: | :---: |
| Symbol | Conditions | Maximum Ratings |  |
| $\mathbf{T}_{\mathrm{vJ}}$ |  | $-55 \ldots+150$ | ${ }^{\circ} \mathrm{C}$ |
| $\mathbf{T}_{\text {stg }}$ |  | $-55 \ldots+125$ | ${ }^{\circ} \mathrm{C}$ |
| $\mathbf{V}_{\text {ISoL }}$ | $\mathrm{I}_{\text {ISoL }} \leq 1 \mathrm{~mA} ; 50 / 60 \mathrm{~Hz}$ | 2500 | $\mathrm{~V}_{\sim}$ |
| $\mathbf{F}_{\mathrm{C}}$ | mounting force with clip | $20 \ldots 120$ | N |


| Symbol | Conditions | Characteristic Values |  |  |
| :--- | :--- | ---: | ---: | ---: |
|  |  | min. | typ. | max. |
| $\mathbf{C}_{\mathrm{p}}$ | coupling capacity between shorted |  | 40 | pF |
|  | pins and mounting tab in the case |  |  |  |
| $\mathbf{d}_{s}, \mathbf{d}_{\mathrm{A}}$ | pin - pin | 1.7 |  | mm |
| $\mathbf{d}_{\mathbf{s}}, \mathbf{d}_{\mathrm{A}}$ | pin - backside metal | 5.5 |  | mm |
| Weight |  |  | 9 | g |

Dimensions in mm ( $1 \mathrm{~mm}=\mathbf{0 . 0 3 9 4}{ }^{\prime \prime}$ )


